

# FINAL PRODUCT/PROCESS CHANGE NOTIFICATION Generic Copy

02-Apr-2007

SUBJECT: ON Semiconductor Initial Product/Process Change Notification #16003

TITLE: Final Product Change Notification for improvement of MSL for SOT223 (discrete) for IPCN15677.

PROPOSED FIRST SHIP DATE: 02-Jun-2007

AFFECTED CHANGE CATEGORY: ON Semiconductor Assembly

AFFECTED PRODUCT DIVISION: All

### FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:

Contact your local ON Semiconductor Sales Office or Dave Culbertson<a href="mailto:dave.culbertson@onsemi.com">dave.culbertson@onsemi.com</a>

SAMPLES: Contact your local ON Semiconductor Sales Office

#### ADDITIONAL RELIABILITY DATA:

Contact your local ON Semiconductor Sales Office or Laura Rivers<a href="mailto:laura.rivers@onsemi.com">laura.rivers@onsemi.com</a>

### **NOTIFICATION TYPE:**

Final Product/Process Change Notification (FPCN)

Final change notification sent to customers. Final Product/Process Change Notification (FPCN) are issued at least 60 days prior to implementation of the change.

ON Semiconductor will consider this change approved unless specific conditions of acceptance are provided in writing within 30 days of receipt of this notice. To do so, contact your local ON Semiconductor Sales Office.

### **DESCRIPTION AND PURPOSE:**

This is a Final Product Change Notification to IPCN 15677 available at <a href="www.onsemi.com">www.onsemi.com</a> to make customers aware that ON Semiconductor is qualifying a new BOM that will improve the moisture sensitivity level (MSL) for the SOT223 discrete package. This FPCN is specific to the listed devices. Devices in these package codes will be rated MSL 1 260.

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QUALIFICATION PLAN:	Results (Rej/SS)
Deviec: PZT751T1G PC MSL1 @ 260C with SAT pre and post MSL H3TRB 85C/85%RH 1008 hrs TC Ta=-65/+150C, 1000 cycles AC/PC 121C, 15psig, 100% RH, 96 hrs IOL Ta=25C, delta Tj=100C max, Ton=Toff=3.5 min, 8500 c HTRB 150C, Bias=80% rated Vr, 1008 hrs	0/248 0/252 0/252 0/252 0/252
Device: SMBF1066T1 PC MSL1 @ 260C with SAT pre and post MSL H3TRB 85C/85%RH 1008 hrs TC Ta=-65/+150C, 1000 cycles AC/PC 121C, 15psig, 100% RH, 96 hrs IOL Ta=25C, delta Tj=100C max, Ton=Toff=3.5 min, 8500 c HTRB 150C, Bias=80% rated Vr, 1008 hrs	0/252 0/252 0/252 0/252 0/252
Device: NIF9N05CLT1 PC MSL1 @ 260C with SAT pre and post MSL H3TRB 85C/85%RH 1008 hrs TC Ta=-65/+150C, 1000 cycles AC/PC 121C, 15psig, 100% RH, 96 hrs HTGB 150C, Bias=100% rated gate V, 1008 hrs	0/248 0/252 0/252 0/252
Device: NIF5003NT1G PC MSL1 @ 260C with SAT pre and post MSL H3TRB 85C/85%RH 1008 hrs TC Ta=-65/+150C, 1000 cycles AC/PC 121C, 15psig, 100% RH, 96 hrs HTGB 150C, Bias=100% rated gate V, 1008 hrs	0/252 0/252 0/252 0/252
Device: NTF3055L08T1G PC MSL1 @ 260C with SAT pre and post MSL H3TRB 85C/85%RH 1008 hrs TC Ta=-65/+150C, 1000 cycles AC/PC 121C, 15psig, 100% RH, 96 hrs HTGB 150C, Bias=100% rated gate V, 1008 hrs	0/252 0/252 0/252 0/252
Device: MCR08MT1G PC MSL1 @ 260C with SAT pre and post MSL H3TRB 85C/85%RH 504 hrs TC Ta=-65/+150C, 500 cycles AC/PC 121C, 15psig, 100% RH, 96 hrs IOL Ta=25C, delta Tj=100C max, Ton=Toff=3.5 min, 7500 c HTRB 150C, Bias=80% rated Vr, 504 hrs	0/252 0/252 0/252 0/252 0/252

#### **ELECTRICAL CHARACTERISTIC SUMMARY:**

No changes to electrical performance occurred.

# CHANGED PART IDENTIFICATION:

Parts with date code of 721 or greater may be manufactured using the new BOM. Devices on this notice will be rated at MSL1 260 at the expiration of this FPCN.

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# **ON Semiconductor**



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#### AFFECTED DEVICE LIST

#### **PART**

BCP68T1

BCP68T1G

BSP52T1

BSP52T1G

BSP52T3

BSP52T3G

MAC08BT1G

MAC08MT1G

MCR08BT1G

MCR08MT1G

MMFT2406T1

MMFT2406T1G

MMFT2406T3

MMFT2955ET1

MMFT2955ET1G

MMFT3055ET1

MMFT3055VLT1

MMFT3055VLT3

MMFT3055VLT3-LF

MMFT3055VT1

MMFT3055VT1G

MMFT960T1

MMFT960T1G

MMJT350T1

MMJT350T1G

MMJT9410T1

MMJT9410T1G

MMJT9435T1

MMJT9435T1G

MMJT9435T3

MMJT9435T3G

NIF5002NT1 NIF5002NT1G

NIF5002NT3

NIF5002NT3G

NIF5003NT1

NIF5003NT1G

NIF5003NT3

NIF5003NT3G

NIF62514T1

NIF62514T1G

NIF62514T3G

NIF9N05CLT1

NIF9N05CLT1G

NIF9N05CLT3

NIF9N05CLT3G

NJT4030PT1G NJT4030PT3G

NMFT3055AVLT1

NMFT3055AVLT3

NSB9435T1

NSB9435T1G

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NTF2955T1

NTF2955T1G

NTF3055-100T1

NTF3055-100T1G

NTF3055-100T3

NTF3055-100T3G

NTF3055-100T3LF

NTF3055-160T1G

NTF3055L108T1

NTF3055L108T1G

NTF3055L108T3

NTF3055L108T3G

NTF3055L108T3LF

NTF3055L108T3LFG

NTF3055L175T1

NTF3055L175T1G

NTF5P03T3

NTF5P03T3G

NTF6P02T3

NTF6P02T3G

NYT103MSTT1G

NYT103NA1

NYT103NSTT1G

PZT651T1

PZT651T1G

PZT751T1

PZT751T1G

SCR5129SG

SMBF1066T1 SMBT1581LT3

SMBT1587T1

SMBT1587T1G

SMFT3055VT3

SMFT3355VLT3

SSVPZT751T1

SSVPZT751T1G

SZT651T1